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November 2013

FQD7P20

P-Channel QFET® MOSFET

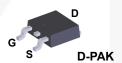
-200 V, -5.7 A, 690 mΩ

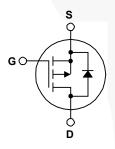
Description

This P-Channel enhancement mode power MOSFET is produced using Fairchild Semiconductor's proprietary planar stripe and DMOS technology. This advanced MOSFET technology has been especially tailored to reduce on-state resistance, and to provide superior switching performance • Low Crss (Typ. 25 pF) and high avalanche energy strength. These devices are suitable for switched mode power supplies, audio amplifier, • 100% Avalanche Tested DC motor control, and variable switching power applications.

Features

- -5.7 A, -200 V, $R_{DS(on)}$ = 690 m Ω (Max.) @ V_{GS} = -10 V, $I_D = -2.85 A$
- Low Gate Charge (Typ. 19 nC)





Absolute Maximum Ratings T_C = 25°C unless otherwise noted.

Symbol	Parameter		FQD7P20TM	Unit
V _{DSS}	Drain-Source Voltage		-200	V
I _D	Drain Current - Continuous (T _C = 25°C)		-5.7	Α
	- Continuous (T _C = 100°C)		-3.6	Α
I _{DM}	Drain Current - Pulsed (N	lote 1)	-22.8	Α
V _{GSS}	Gate-Source Voltage		± 30	V
E _{AS}	Single Pulsed Avalanche Energy (Note 2)		570	mJ
I _{AR}	Avalanche Current (N	Note 1)	-5.7	Α
E _{AR}	Repetitive Avalanche Energy (Note 1		5.5	mJ
dv/dt	Peak Diode Recovery dv/dt (Note 3)		-5.5	V/ns
P _D	Power Dissipation (T _A = 25°C) *		2.5	W
	Power Dissipation (T _C = 25°C) - Derate above 25°C		55	W
			0.44	W/°C
T _J , T _{STG}	Operating and Storage Temperature Range		-55 to +150	°C
T _L	Maximum Lead Temperature for Soldering, 1/8" from Case for 5 Seconds.		300	°C

Thermal Characteristics

Symbol	Parameter	FQD7P20TM	Unit
$R_{\theta JC}$	Thermal Resistance, Junction to Case, Max.	2.27	
В	Thermal Resistance, Junction to Ambient (Minimum Pad of 2-oz Copper), Max.	110	°C/W
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient (*1 in ² Pad of 2-oz Copper), Max.	50	

Package Marking and Ordering Information

Part Number	Top Mark	Package	Packing Method	Reel Size	Tape Width	Quantity
FQD7P20TM	FQD7P20	D-PAK	Tape and Reel	330 mm	16 mm	2500 units

Flectrical Characteristics

Symbol	Parameter	Test Conditions	Min.	Тур.	Max.	Uni
Off Cha	aracteristics					
BV _{DSS}	Drain-Source Breakdown Voltage	$V_{GS} = 0 \text{ V}, I_D = -250 \mu\text{A}$	-200			V
ΔBV _{DSS} / ΔT	Breakdown Voltage Temperature Coefficient	I _D = -250 μA, Referenced to 25°C		-0.1		V/°C
I _{DSS}	Zero Cala Vallana Basis Consul	V _{DS} = -200 V, V _{GS} = 0 V			-1	μΑ
Zero Gate Voltage Drain	Zero Gate Voltage Drain Current	V _{DS} = -160 V, T _C = 125°C			-10	μΑ
I _{GSSF}	Gate-Body Leakage Current, Forward	V _{GS} = -30 V, V _{DS} = 0 V			-100	nA
I _{GSSR}	Gate-Body Leakage Current, Reverse	V _{GS} = 30 V, V _{DS} = 0 V			100	nA
On Cha	aracteristics					
V _{GS(th)}	Gate Threshold Voltage	$V_{DS} = V_{GS}, I_{D} = -250 \mu\text{A}$	-3.0		-5.0	V
R _{DS(on)}	Static Drain-Source On-Resistance	V _{GS} = -10 V, I _D = -2.85 A		0.54	0.69	Ω
9 _{FS}	Forward Transconductance	V _{DS} = -40 V, I _D = -2.85 A		3.7		S
Dynam	ic Characteristics					
C _{iss}	Input Capacitance	$V_{DS} = -25 \text{ V}, V_{GS} = 0 \text{ V},$	\	590	770	pF
C _{oss}	Output Capacitance	f = 1.0 MHz		140	180	pF
C _{rss}	Reverse Transfer Capacitance			25	35	pF
Switch	ing Characteristics					
t _{d(on)}	Turn-On Delay Time	V _{DD} = -100 V, I _D = -7.3 A,		15	40	ns
t _r	Turn-On Rise Time	$R_G = 25 \Omega$		110	230	ns
t _{d(off)}	Turn-Off Delay Time	11.6 - 20.32		30	70	ns
t _f	Turn-Off Fall Time	(Note 4)		42	90	ns
Qg	Total Gate Charge	$V_{DS} = -160 \text{ V}, I_D = -7.3 \text{ A},$		19	25	nC
Q _{gs}	Gate-Source Charge	V _{GS} = -10 V		4.6		nC
Q _{gd}	Gate-Drain Charge	(Note 4)	/	9.5		nC
Drain S	Source Diode Characteristics a	nd Maximum Patings				
l _S	Maximum Continuous Drain-Source Did				-5.7	Α
I _{SM}	Maximum Continuous Brain-Source Bio				-22.8	A
- IVI C		V _{GS} = 0 V, I _S = -5.7 A			-5.0	V
	Drain-Source Diode Forward Voltage	V C C - U V. I C 3 / A				
V _{SD}	Drain-Source Diode Forward Voltage Reverse Recovery Time	$V_{GS} = 0 \text{ V, } I_S = -3.7 \text{ A}$ $V_{GS} = 0 \text{ V, } I_S = -7.3 \text{ A,}$		180	-5.0	ns

- Notes. 1. Repetitive rating: pulse-width limited by maximum junction temperature. 2. L = 26.3 mH, I_{AS} = -5.7 A, V_{DD} = -50 V, R_{G} = 25 Ω , starting T_{J} = 25°C. 3. $I_{SD} \le$ -7.3 A, di/dt \le 300 A/µs, $V_{DD} \le$ BV_{DSS}, starting T_{J} = 25°C. 4. Essentially independent of operating temperature.

Typical Characteristics

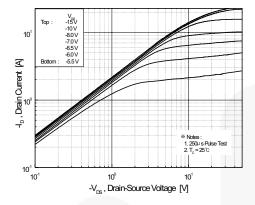


Figure 1. On-Region Characteristics

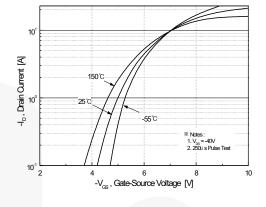


Figure 2. Transfer Characteristics

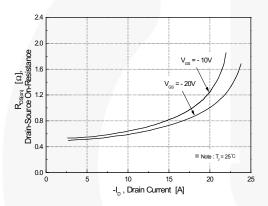


Figure 3. On-Resistance Variation vs. Drain Current and Gate Voltage

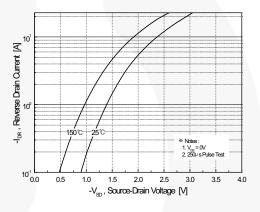


Figure 4. Body Diode Forward Voltage Variation vs. Source Current and Temperature

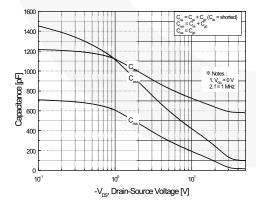


Figure 5. Capacitance Characteristics

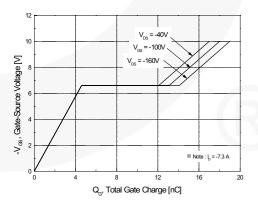


Figure 6. Gate Charge Characteristics

Typical Characteristics (Continued)

Figure 7. Breakdown Voltage Variation vs. Temperature

T,, Junction Temperature [°C]

150

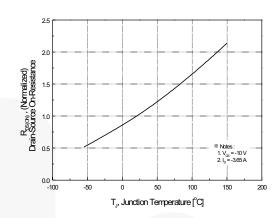


Figure 8. On-Resistance Variation vs. Temperature

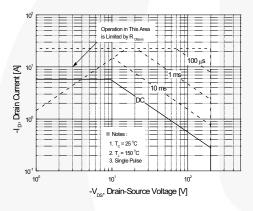


Figure 9. Maximum Safe Operating Area

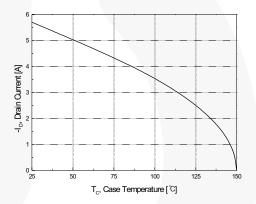


Figure 10. Maximum Drain Current vs. Case Temperature

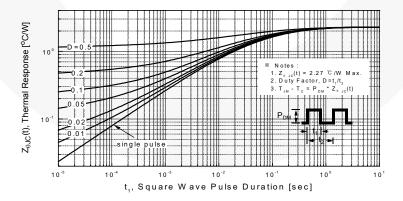


Figure 11. Transient Thermal Response Curve

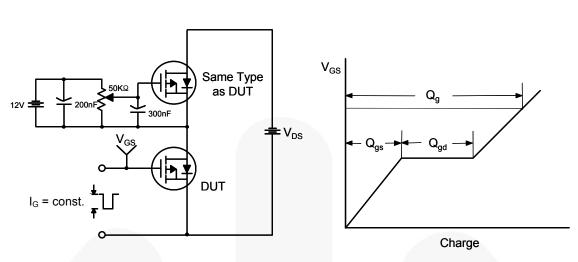


Figure 12. Gate Charge Test Circuit & Waveform

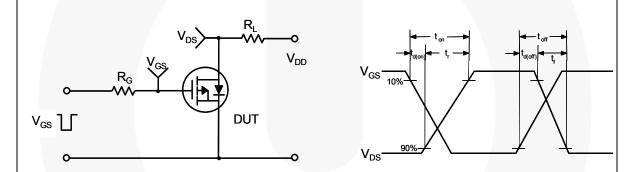


Figure 13. Resistive Switching Test Circuit & Waveforms

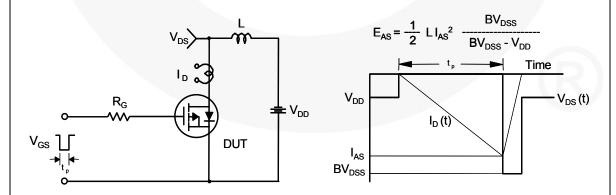
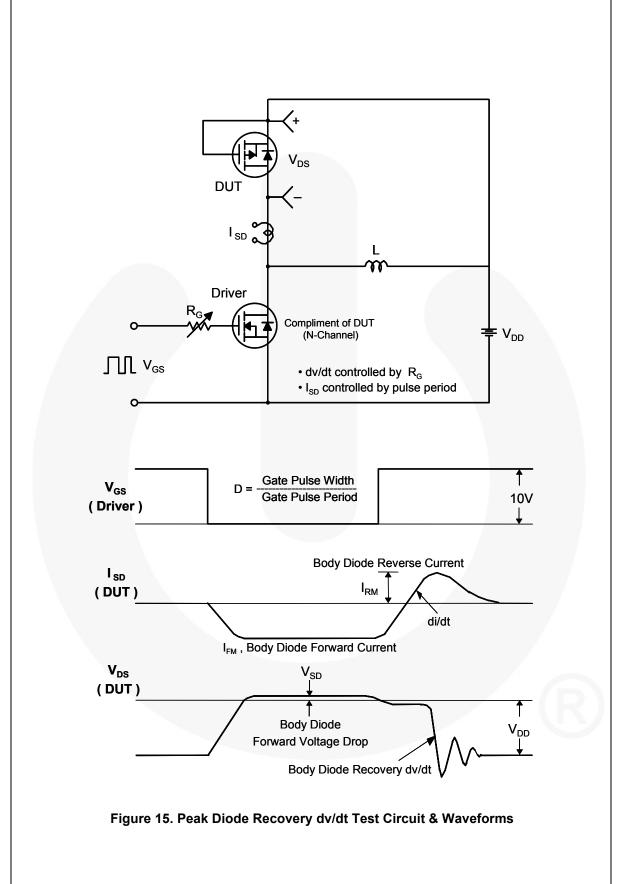


Figure 14. Unclamped Inductive Switching Test Circuit & Waveforms



Mechanical Dimensions

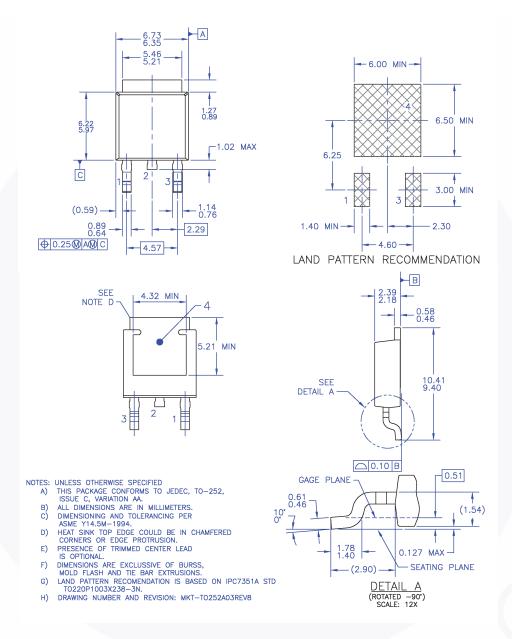


Figure 16. TO252 (D-PAK), Molded, 3-Lead, Option AA&AB

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